

# OKI electronic components

## OCS33

### Optical PNPN Switches

#### GENERAL DESCRIPTION

The OCS33 is an optical PNPN switch, combining an infrared light emitting diode and a PNPN element(photothyristor) in a single 8-pin plastic package. The device is capable of withstanding high voltages. The output PNPN element of the OCS33 forms a half-bridge configuration. The output PNPN element of the OCS33 forms a half-bridge configuration. The OCS33 is designed for extended life-time operation, making the device ideal for applications such as communications and telephone switching equipment.

#### FEATURES

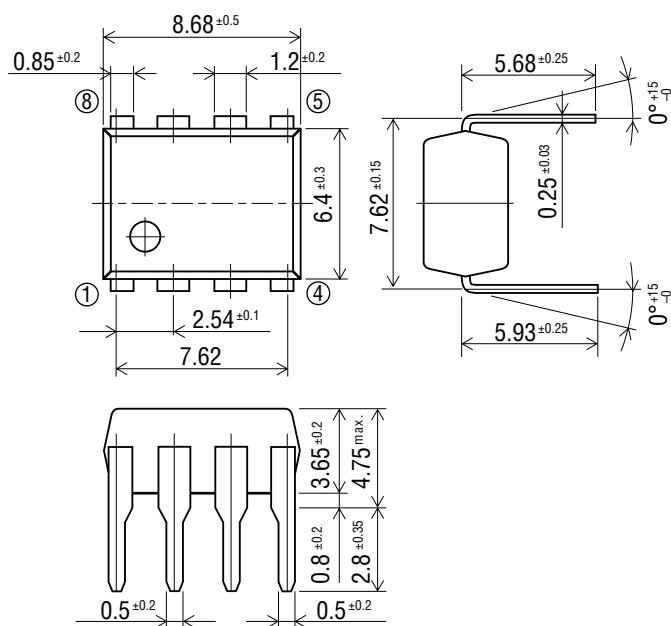
- Forward blocking voltage ( $V_{BO}$ ,  $V_{BD}$ ): 320 V (Min.)
- Trigger input current ( $I_{GO}$ ): 15 mA (Max.)

#### APPLICATIONS

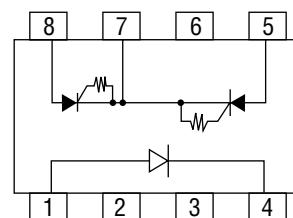
- Electronic automatic exchange
- Key telephone system
- Contactless switch
- Optically coupled circuits.

#### PIN CONFIGURATION

(Unit: mm)



• Pin Connection Diagram



- |            |                 |
|------------|-----------------|
| 1: Anode   | (LED)           |
| 2: NC      | (No connection) |
| 3: NC      | (No connection) |
| 4: Cathode | (LED)           |
| 5: Output  | (PNPN)          |
| 6: NC      | (No connection) |
| 7: Output  | (PNPN)          |
| 8: Output  | (PNPN)          |

## ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Test Condition	Rating	Unit
Input (LED)	Forward Current	I <sub>G</sub>	Ta=25°C	60	mA
	Reverse Voltage	V <sub>RL</sub>		5	V
Output (PNPN)	Forward Blocking Voltage	V <sub>BO</sub>	Ta=25°C	350	V
	Reverse Voltage	V <sub>BD</sub>		350	V
	Continuous ON-State Current	I <sub>F</sub>		100	mA
	Surge ON-State Current *	I <sub>SUG</sub>		1.4	A
	Isolation Voltage	V <sub>I-O</sub>		1500	V
Operating Temperature		T <sub>opr</sub>	—	-20 to +70	°C
Storage Temperature		T <sub>stg</sub>	—	-30 to +100	°C

\* A single 1 ms pulse

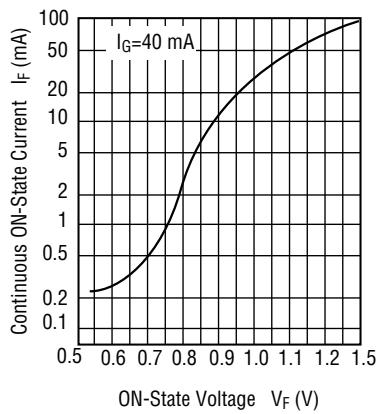
## ELECTRICAL CHARACTERISTICS

(Ambient Temperature Ta=25°C)

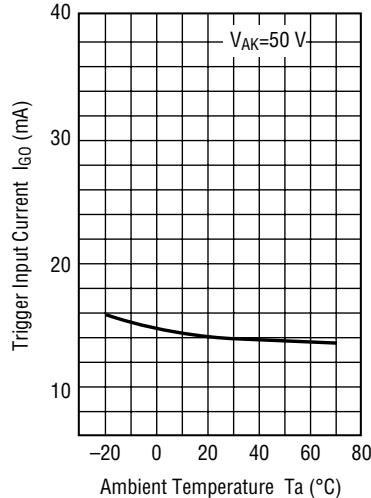
Parameter		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Characteristics	Forward Voltage	V <sub>FL</sub>	I <sub>G</sub> =40 mA	—	—	1.4	V
	Reverse Current	I <sub>RL</sub>	V <sub>RL</sub> =5 V	—	—	5	μA
Output Characteristics	OFF-State Current	I <sub>BO</sub>	V <sub>AK</sub> =320 V	—	—	5	μA
	Reverse Voltage	I <sub>BD</sub>	V <sub>AK</sub> =320 V	—	—	5	μA
	ON-State Voltage	V <sub>F</sub>	I <sub>F</sub> =20 mA, I <sub>G</sub> =40 mA	—	—	1.0	V
	dV/dt Capability	dV/dt	dt=0.1 μs	120	—	—	V/0.1μs
	Holding Current	I <sub>H</sub>	ON to OFF	—	—	1.3	mA
Coupled Characteristics	Trigger Input Current	I <sub>GO</sub>	V <sub>AK</sub> =500 VDC	—	—	15	mA

## TYPICAL CHARACTERISTICS

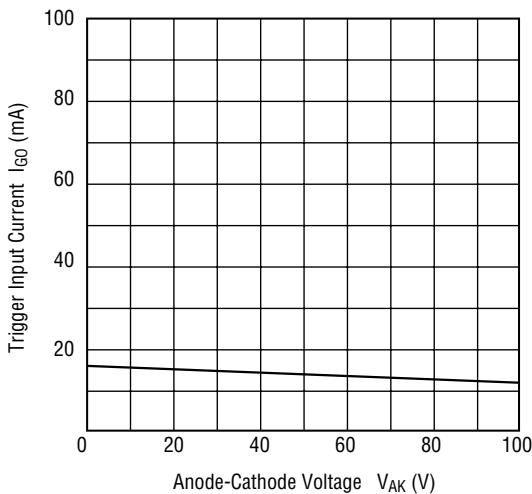
- Continuous ON-State Current vs. ON-State Voltage ( $T_a=25^\circ C$ )



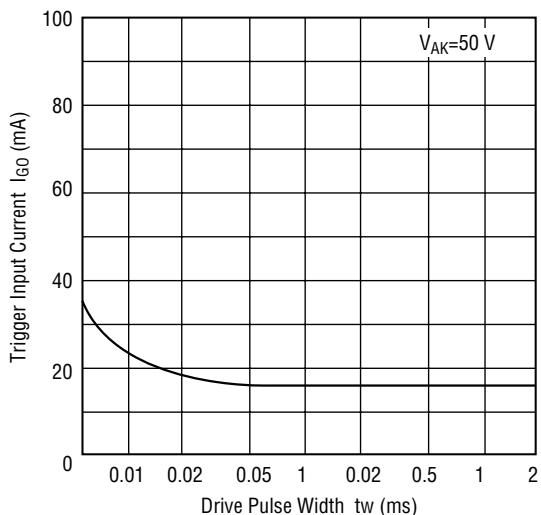
- Trigger Input Current vs. Ambient Temperature



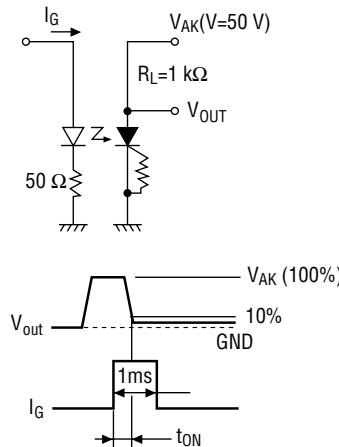
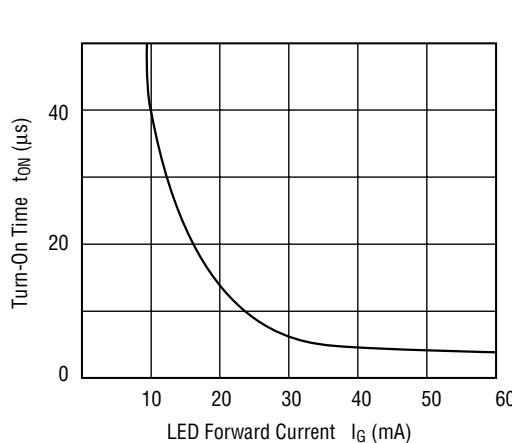
- Trigger Input Current vs. Anode-Cathode Voltage ( $T_a=25^\circ C$ )



- Trigger Input Current vs. Drive Pulse Width ( $T_a=25^\circ C$ )



- Turn-On Time vs. LED Forward Current ( $T_a=25^\circ\text{C}$ )



- dV/dt Capability vs. Ambient Temperature
- Input LED Foward Current vs. Voltage

